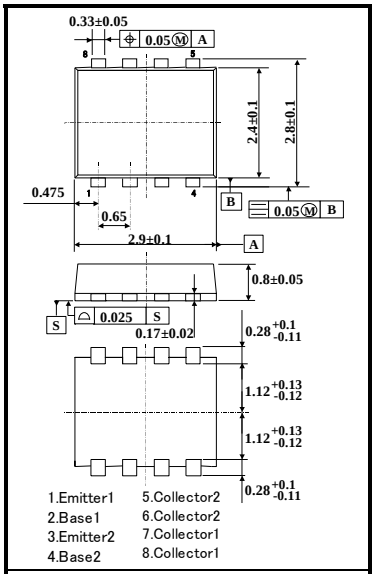
TOSHIBA Transistor Silicon NPN Epitaxial Type

TPCP8701

Portable Equipment Applications
Switching Applications
Inverter Lighting Applications

- Small footprint due to small and thin package
- High DC current gain : h_{FE} = 400 to 1000 (I_C = 0.3 A)
- Low collector-emitter saturation : $V_{CE\ (sat)}$ = 0.14 V (max)
- High-speed switching : t_f = 120 ns (typ.)

Unit: mm



JEDEC	—
JEITA	—
TOSHIBA	2-3V1C

Weight: 0.017 g (typ.)

Maximum Ratings (Ta = 25°C)

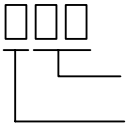
Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	100	V
Collector-emitter voltage		V_{CEX}	80	V
		V_{CEO}	50	V
Emitter-base voltage		V_{EBO}	7	V
Collector current	DC (Note 1)	I_C	3.0	A
	Pulse (Note 1)	I_{CP}	5.0	
Base current		I_B	300	mA
Collector power dissipation (t = 10s)	Single-device operation	Pc (Note 2)	1.77	W
	Single-device value at dual operation		0.95	
Collector power dissipation (DC)	Single-device operation	Pc (Note 2)	0.94	W
	Single-device value at dual operation		0.54	
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

Note 1: Please use devices on condition that the junction temperature is below 150°C.

Note 2: Mounted on FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm^2)

Note 3: ● on lower left on the marking indicates Pin 1.

※ Weekly code: (Three digits)



Week of manufacture
(01 for first week of year, continues up to 52 or 53)

Year of manufacture
(One low-order digits of calendar year)

Figure 1. Circuit configuration (Top View)

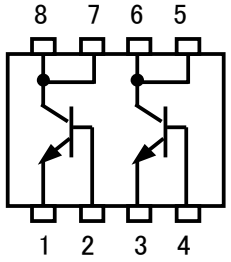
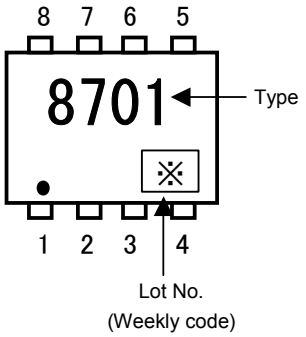


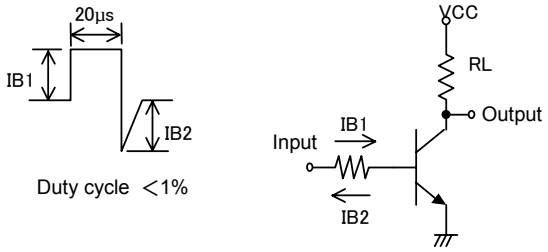
Figure 2. Marking (Note 3)



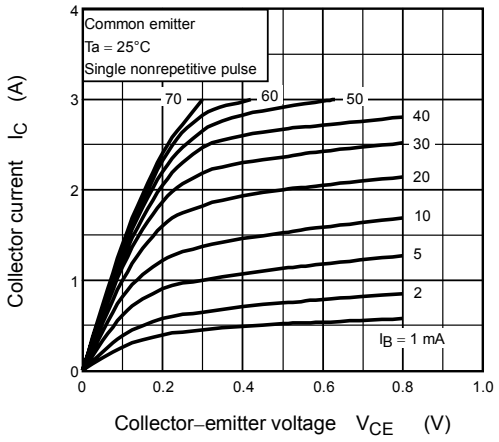
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	V_{CB} = 100 V, I_E = 0	—	—	100	nA
Emitter cut-off current		I_{EBO}	V_{EB} = 7 V, I_C = 0	—	—	100	nA
Collector-emitter brakedown voltage		$V_{(BR)\ CEO}$	I_C = 10 mA, I_B = 0	50	—	—	V
DC current gain		h_{FE} (1)	V_{CE} = 2 V, I_C = 0.3 A	400	—	1000	
		h_{FE} (2)	V_{CE} = 2 V, I_C = 1 A	200	—	—	
Collector-emitter saturation voltage		$V_{CE\ (sat)}$	I_C = 1 A, I_B = 20 mA	—	—	0.14	V
Base-emitter saturation voltage		$V_{BE\ (sat)}$	I_C = 1 A, I_B = 20 mA	—	—	1.10	V
Collector output capacitance		C_{ob}	V_{CB} = 10 V, I_E = 0, f = 1MHz	—	13	—	pF
Switching time	Rise time	t_r	See Figure 3 circuit diagram $V_{CC} \simeq$ 30 V, R_L = 30 Ω $I_{B1} = -I_{B2}$ = 33.3 mA	—	40	—	ns
	Storage time	t_{stg}		—	500	—	
	Fall time	t_f		—	120	—	

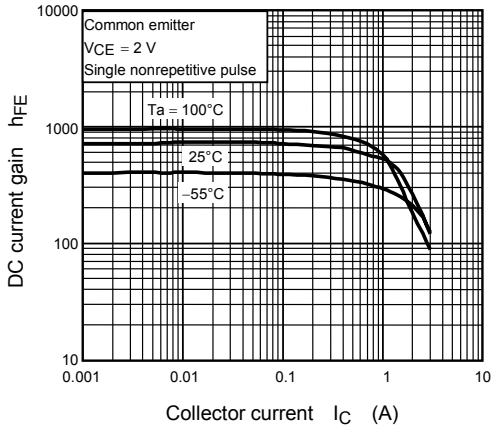
Figure 3. Switching Time Test Circuit & Timing Chart



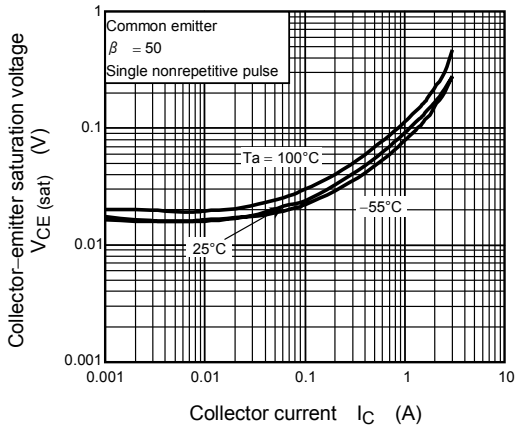
$I_C - V_{CE}$



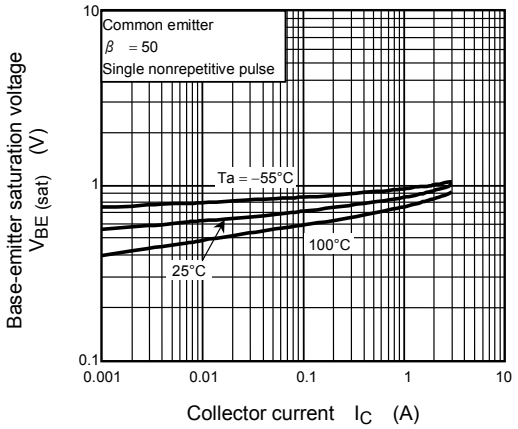
$h_{FE} - I_C$



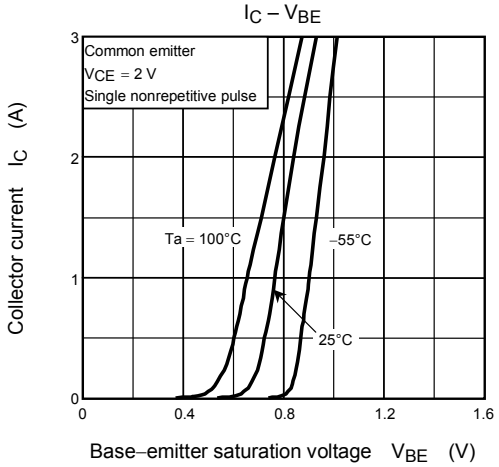
$V_{CE\ (sat)} - I_C$



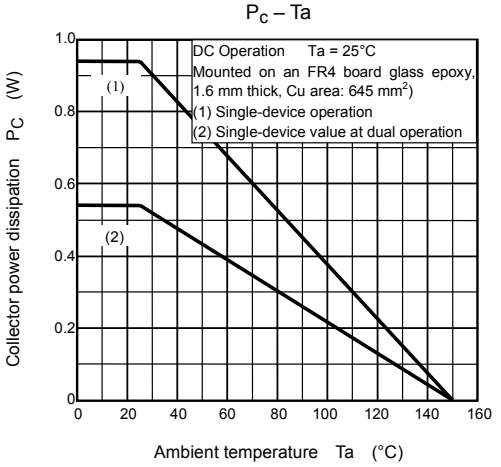
$V_{BE\ (sat)} - I_C$



$I_C - V_{BE}$

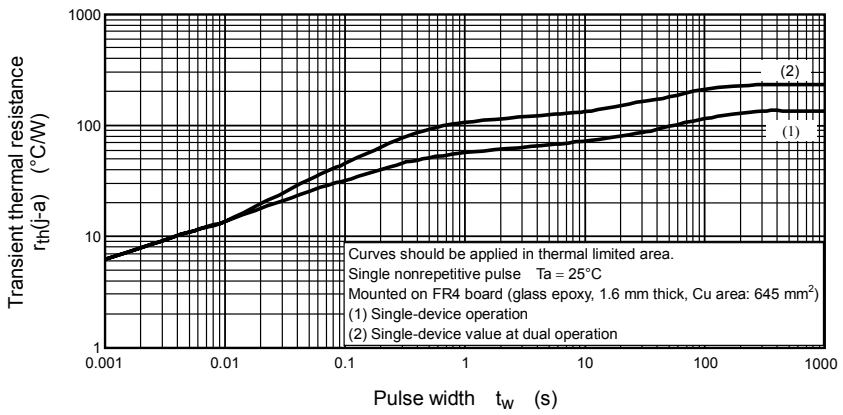


$P_c - Ta$

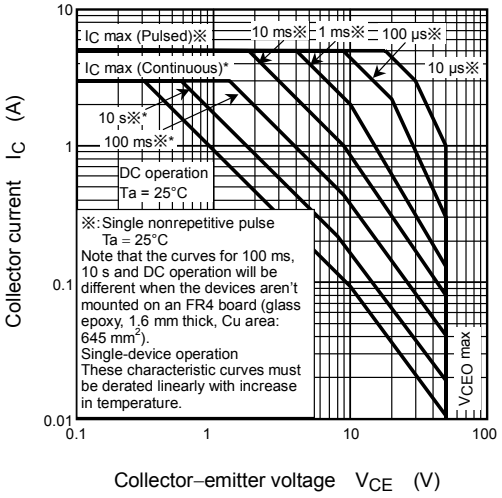


(2)

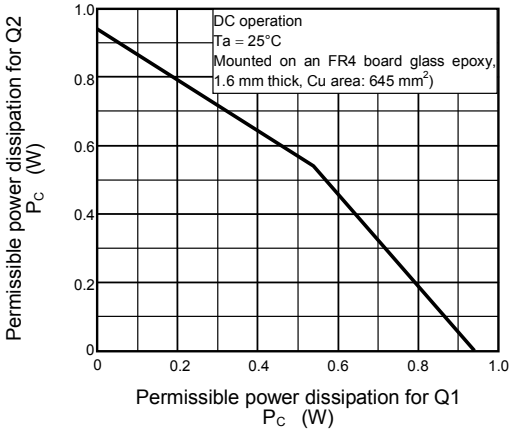
$r_{th} - t_w$



Safe operating area



Permissible Power Dissipation for Simultaneous Operation



Collector power dissipation at the single-device operation is 0.94W.

Collector power dissipation at the single-device value at dual operation is 0.54W.

Collector power dissipation at the dual operation is set to 1.08W.

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